AM4533C

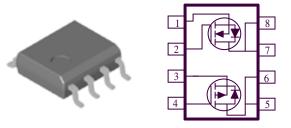
Analog Power

P & N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	I _D (A)	
20	$40 @ V_{GS} = 2.5V$	6.0	
20	$31 @ V_{GS} = 4.5V$	6.9	
-20	$80 @ V_{GS} = -2.5V$	-4.2	
	52 @ $V_{GS} = -4.5V$	-5.2	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	N-Channel	P-Channel	Units	
Drain-Source Voltage		V _{DS}	20	-20	V	
Gate-Source Voltage		V _{GS}	±8	±8		
	T _A =25°C	I_	6.9	-5.2	А	
Continuous Drain Current ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ID	5.4	-6.8		
Pulsed Drain Current ^b		I _{DM}	20	-20		
Continuous Source Current (Diode Conduction) ^a		Is	1.3 -1.3		Α	
Derver Discinction ^a	T _A =25°C	P.,	2.1	2.1	W	
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	I D	1.3	1.3		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to	°C		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	62.5	°C/W	
	Steady-State		110	°C/W	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

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Parameter		LESS OTHERWISE NOT Test Conditions	Limits				
	Symbol		Ch	Min	Тур	Max	Unit
Static						•	
Gate-Threshold Voltage	V _{GS(th)}	$V_{GS} = V_{DS}$, $I_D = 250 \text{ uA}$	Ν	0.4			v
	• GS(th)	$V_{GS} = V_{DS}$, $I_D = -250 \text{ uA}$	Р	-0.4			
Gate-Body Leakage	I _{GSS}	$V_{GS} = -8 V, V_{DS} = 0 V$	Р			±100	nA
Gate-Dody Leakage	-G22	$V_{GS} = 8 V, V_{DS} = 0 V$	Ν			±100	
Zero Gate Voltage Drain Current	I _{DSS}	VDS = -16 V, $VGS = 0 V$	Р			-1	uA
	-D22	$V_{DS} = 16 V, V_{GS} = 0 V$	Ν			1	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 4.5 V$	Ν	20			Α
On-State Drain Current	-D(on)	$V_{DS} = -5 V, V_{GS} = -4.5 V$	Р	-20			
		VGS = 4.5 V, ID = 6.9 A	Ν			31	mΩ
Drain-Source On-Resistance ^A	r _{DS(on)}	VGS = 2.5 V, ID = 6 A	19			40	
Dram-Source On-Resistance	¹ DS(on)	VGS = -4.5 V, ID = -5.2 A	Р			52	
		VGS = -2.5 V, $ID = -4.2 A$				80	
Forward Tranconductance ^A	a	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 6.9 \text{ A}$	Ν		25		S
	$g_{\rm fs}$	V_{DS} = -15 V, I_D = -5.2 A	Р		10		
Dynamic							
Total Gate Charge	0	$\begin{array}{c c} Q_g & & & \\ \hline Q_{gs} & & \\ Q_{gs} & & \\ Q_{gd} & & \\ \hline Q_{gd} & & \\ \hline \end{array}$	Ν		6.0		nC
Total Gate Charge	≺g		Р		25		
Gate-Source Charge	0		Ν		1.0		
	≺gs		Р		2.4		
Gate-Drain Charge	0,		Ν		1.5		
Gate Drain Charge	≺gd		Р		3.9		
Turn-On Delay Time	t _{d(on)}	N-Chaneel $V_{\text{DD}}{=}15V, V_{\text{GS}}{=}4.5V, \text{ID}{=}1A \ , \\ R_{\text{GEN}}{=}6\Omega, \label{eq:generalized}$	Ν		7.4		nS
Turi on Delay Tine	^c d(on)		Р		7.6		
Rise Time	t _r		Ν		4		
	ч		Р		6.8		
Turn-Off Delay Time	t _{d(off)}	P-Channel			22.2		
Tun On Deny Time	-d(011)	VDD=-15V, VGS=-4.5V, ID=-1A RGEN= 6Ω	Р		33.6		
Fall-Time	t _f	KOEN-022	Ν		3.6		
	4		Р		23.2		

Notes

a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

b. Guaranteed by design, not subject to production testing.

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